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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/711,644	09/29/2004	Wei Lu	FIS920040037US1	5643	
29371 7590 05/01/2006 CANTOR COLBURN LLP - IBM FISHKILL 55 GRIFFIN ROAD SOUTH BLOOMFIELD, CT 06002			EXAMINER		
			YANTORNO,	YANTORNO, JENNIFER M	
			ART UNIT	PAPER NUMBER	
	,			2881	
			DATE MAILED: 05/01/2006		

Please find below and/or attached an Office communication concerning this application or proceeding.

-		Application No.	Applicant(s)				
Office Action Summary The MAILING DATE of this communication ap							
		10/711,644	LU, WEI				
		Examiner	Art Unit				
		Jennifer Yantorno	2881				
Period for Reply		ears on the cover sheet with the	e con esponacione dadress				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1)⊠ Respons	Responsive to communication(s) filed on 21 April 2006.						
<i>,</i> —	This action is FINAL. 2b)⊠ This action is non-final.						
•	s application is in condition for allowar						
ciosea in	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims .							
	4) Claim(s) 1-16 is/are pending in the application.						
•	4a) Of the above claim(s) is/are withdrawn from consideration.						
·— · ·	5) Claim(s) is/are allowed.						
•	<u>1-16</u> is/are rejected. is/are objected to.		·				
, —	are subject to restriction and/o	r election requirement.					
	•	• ,					
Application Pape							
	ification is objected to by the Examine		asted to but he Everiner				
	ring(s) filed on <u>18 November 2004</u> is/a						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority under 35 U.S.C. § 119 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
	eagment is made of a claim for foreign)□ Some * c)□ None of:	priority drider 35 O.S.C. § 118	7(a)-(u) 01 (1).				
1. ☐ Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau (PCT Rule 17.2(a)).							
* See the attached detailed Office action for a list of the certified copies not received.							
Attachment(s)							
1) Notice of Refere	nary (PTO-413) il Date						
	person's Patent Drawing Review (PTO-948) Iosure Statement(s) (PTO-1449 or PTO/SB/08) I Date	-: T	al Patent Application (PTO-152)				

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DETAILED ACTION

Response to Arguments

Applicant's arguments, filed 4/21/2006, with respect to claims 1-16 have been fully considered and are persuasive. The final rejection of claims 1-16 has been withdrawn. A new non-final rejection is below.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-5, 8-13, and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Musil et al. (US 6,753,538), in view of Chang et al. (US 6,646,259).

Regarding claims 1 and 9, '538 teaches a method for preparing a specimen for application of microanalysis thereto, the method comprising forming an initial conductive layer over only a localized area of interest, without blanket coverage of said initial conductive layer, said initial conductive layer formed through low-energy beam deposition process (Col. 3, II. 65-Col. 4, II. 3, Col. 4, II. 52-65, Col. 5, II. 24, Col. 6, II. 53, Col. 12, II. 48-54). '259 teaches removing a volume of material surrounding the area of interest by forming a pair of trenches in a bulk material having the area of interest formed thereon, thereby forming a membrane including the area of interest sand the initial conductive layer over the area interest, and removing the membrane form the bulk material (Col. 4, II. 7-17). It would have been obvious to form trenches in a bulk material

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thereby forming a membrane and removing the membrane from the bulk material as this is a well-known method of preparing TEM samples.

Regarding claim 2, '538 teaches that the low-energy beam deposition process comprises electron beam deposition (Col. 3, II. 65-Col. 4, II. 3, Col. 4, II. 52-65, Col. 5, II. 24, Col. 6, II. 53, Col. 12, II. 48-54).

Regarding claims 3 and 11, '538 teaches that the conductive later is made of tungsten (Col. 12, II. 48-54).

Regarding claims 4 and 12, '259 teaches that the conductive layer is formed at a thickness of up to 20 nm (Col 3, II. 41-43).

Regarding claims 5 and 13, '259 teaches that the conductive layer is form over an area of about 1 micron by about 10 microns (Col 4, II. 7-12).

Regarding claims 8 and 16, '259 teaches removing a volume of material surrounding the area of interest is implemented by FIB milling (Col. 4, II. 7-12)

Regarding claim 10, '259 teaches that the microanalysis comprises tunneling electron microscopy (Col. 4, II. 7-12).

Claims 6, 7, 14, and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Musil et al. (US 6,753,538), in view of Chang et al. (US 6,646,259 B2), further in view of Engelmann et al. (US 6,303,399 B1).

Regarding claims 6, 7, 14, and 15, the aforementioned prior art meets all claim limitation with the exception of implementing high-energy ion beam deposition for thickening the initial conductive layer. '399 teaches implementing high-energy ion beam deposition for the conductive layer (Col. 5, II. 55-59). It would have been obvious to one

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skilled in the art at the time of the invention to implementing high-energy ion beam deposition for thickening the initial conductive layer as this method is faster than low-energy electron beam deposition and is notoriously known in the art.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jennifer Yantorno whose telephone number is (571) 272-5918. The examiner can normally be reached on Monday-Friday, 9 am - 5 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Lee can be reached on (571) 272-2477. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

JΥ

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